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Kims Ref. No.: OPP-EZ-2000-0117-US-C2

LGP's Ref. No.: P00-083US004D1

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

n re Application of:	)
Chae Gee Sung	) )
Serial No.: To Be Assigned	) )
Filing Date: Herewith	) )
For: Semiconductor Transistor Having Interface Layer Between Semiconductor And Insulating Layers	))))

## PRELIMINARY AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

Prior to examination of the above-identified application, please amend the application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks begin on page 5 of this paper.